

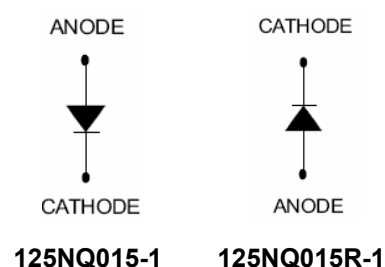
125NQ015/R-1 SCHOTTKY RECTIFIER

Applications:

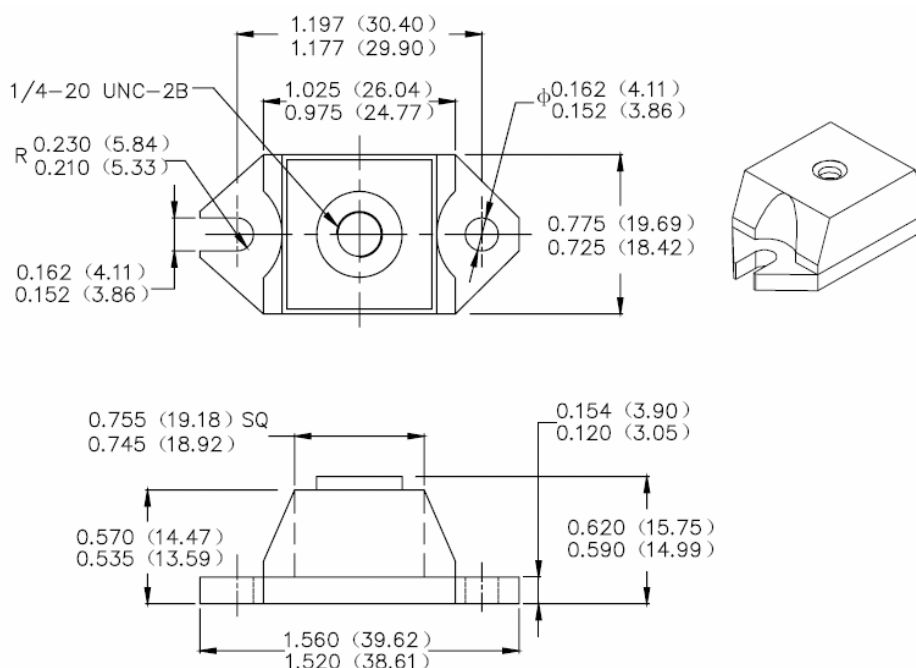
- Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 125°C T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm



PRM1-1(HALF PAK Module)

MARKING, MOLDING RESIN

Marking for 125NQ015/R-1, 1st row SS YYWWL, 2nd row 125NQ015-1/125NQ015R-1

Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

Technical Data
Data Sheet N1235, Rev. -

Green Products

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	15(DC) 25(Working)	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 71^\circ\text{C}$, rectangular wave form	120	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	2040	A
Non-Repetitive Avalanche Energy	E_{AS}	$T_J = 25^\circ\text{C}$, $I_{AS} = 2\text{A}$, $L = 4.5\text{mH}$	9	mJ
Repetitive Avalanche Current	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical	2	A

Electrical Characteristics:

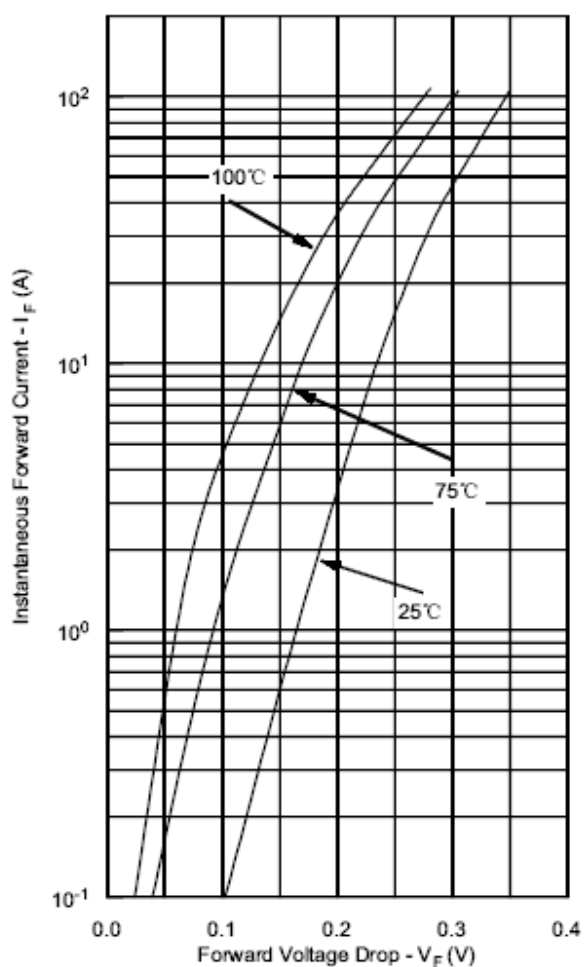
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	@ 120A, Pulse, $T_J = 25^\circ\text{C}$	0.39	V
	V_{F2}	@ 240A, Pulse, $T_J = 25^\circ\text{C}$	0.52	
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	40	mA
	I_{R2}	@ $V_R = \text{rated } V_R$ $T_J = 100^\circ\text{C}$	2000	
	I_{R3}	@ $V_R = \text{rated } V_R$ $T_J = 100^\circ\text{C}$	1780	
	I_{R4}	@ $V_R = \text{rated } V_R$ $T_J = 100^\circ\text{C}$	1080	
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{V}$, $T_C = 25^\circ\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	7700	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μs

- Pulse Width < 300 μs , Duty Cycle < 2%

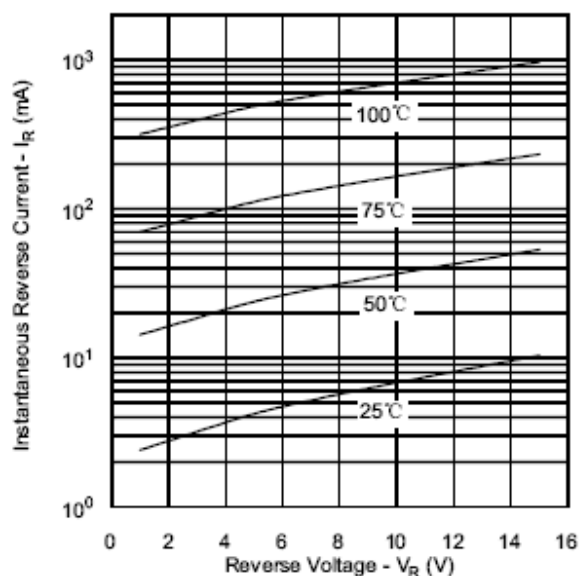
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Max. Junction Temperature	T _J	-	-55 to +125		°C
Max. Storage Temperature	T _{stg}	-	-55 to +150		°C
Maximum Thermal Resistance Junction to Case	R _{θJC}	DC operation	0.40		°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	T _M	Non-lubricated threads	Mounting Torque	23(min) 29(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

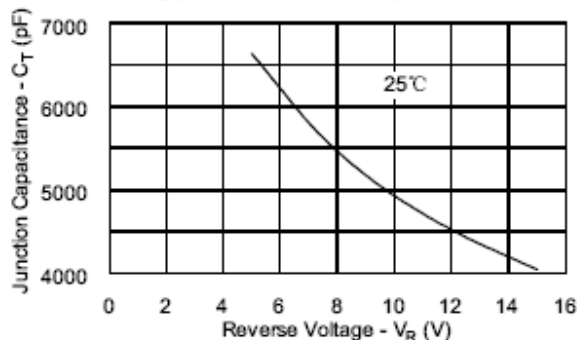
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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